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High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.55$ V at $I_F = 5.0$ A



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DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V _{RRM}	150 V			
I _{FSM}	160 A			
V_F at $I_F = 20$ A	0.75 V			
T _J max.	150 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Single			

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



 Material categorization: HALOGEN for definitions of compliance please see FREE www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VB20150S	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	150	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	160	А	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5.0 A	T _A = 25 °C	V _F	0.69	-	V	
	I _F = 10 A			0.84	-		
	I _F = 20 A			1.15	1.43		
	I _F = 5.0 A	T _A = 125 °C		0.55	-		
	I _F = 10 A			0.64	-		
	I _F = 20 A			0.75	0.82		
Reverse current per diode ⁽²⁾	V _R = 100 V	T _A = 25 °C	I _R	2	-	μA	
		T _A = 125 °C		2.5	-	mA	
	V _R = 150 V	T _A = 25 °C		-	250	μA	
		T _A = 125 °C		5	25	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

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 1
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VB20150S-M3

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VB20150S	UNIT		
Typical thermal resistance	$R_{ ext{ heta}JC}$	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB20150S-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VB20150S-M3/8W	1.39	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

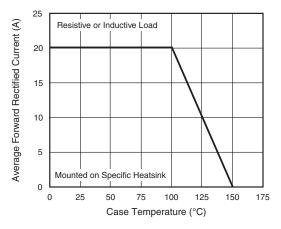


Fig. 1 - Maximum Forward Current Derating Curve

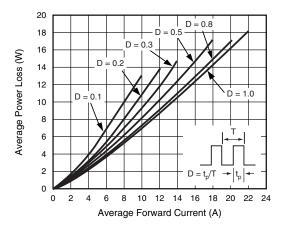


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

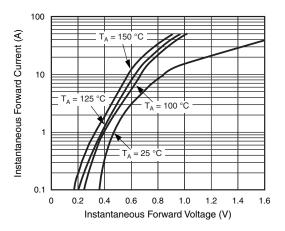


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

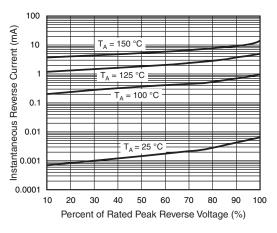
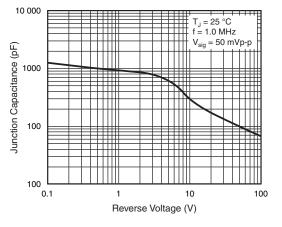


Fig. 4 - Typical Reverse Characteristics Per Diode



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Fig. 5 - Typical Junction Capacitance Per Diode

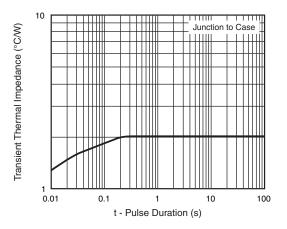
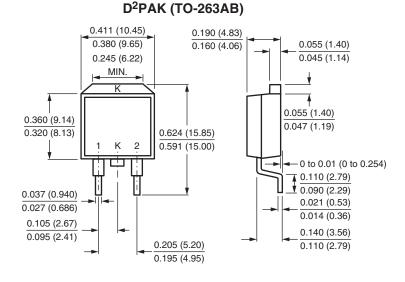
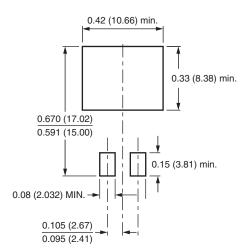


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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